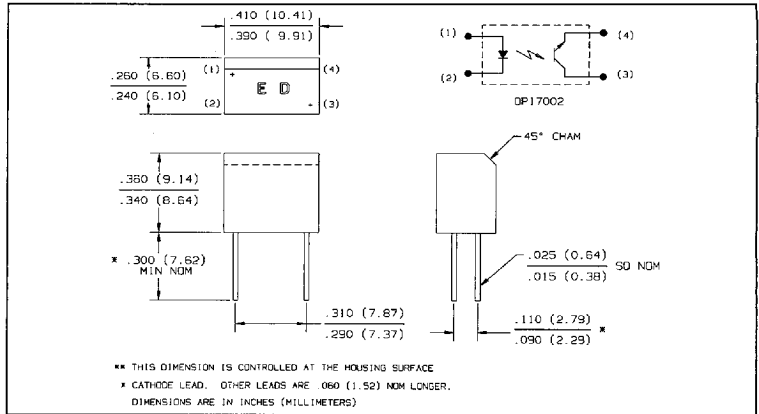
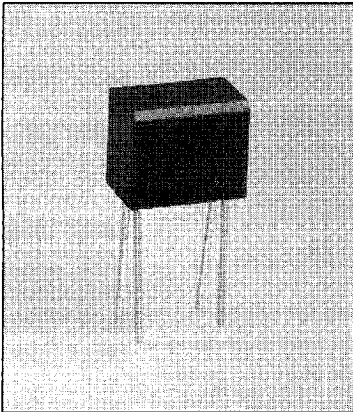


Optically Coupled Isolators

Types OPI7002, OPI7010



Features

- 6kV electrical isolation
- Low cost plastic housing
- UL recognized File No. E58730⁽⁴⁾
- Phototransistor output

Description

The OPI7002 and OPI7010 each consist of an infrared emitting diode coupled to an NPN silicon phototransistor. The LED and sensor are encased in a black, low-cost plastic housing. Pin spacing is compatible with standard dual-in-line packages.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Input-to-Output Isolation Voltage	$\pm 6\text{ kVDC}^{(1)(4)}$
Operating and Storage Temperature Range	-40°C to $+85^\circ\text{C}$
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 sec. with soldering iron]	$260^\circ\text{C}^{(2)}$

Input Diode

Forward DC Current	50 mA
Peak Forward Current (1 μs pulse width, 300 pps)	3.0 A
Reverse Voltage	2.0 V
Power Dissipation	100 mW ⁽³⁾

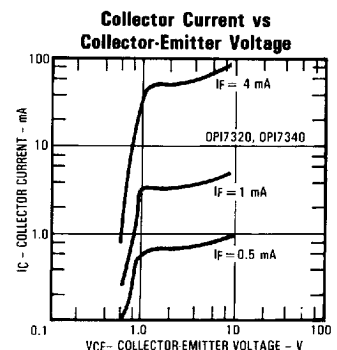
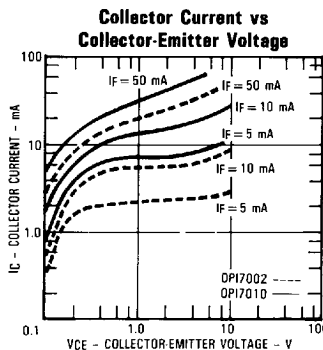
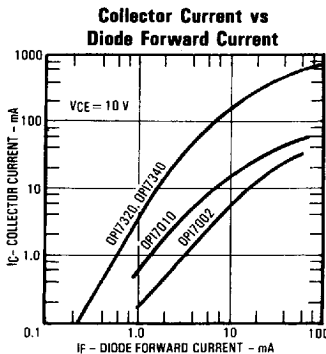
Output Phototransistor

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5.0 V
Power Dissipation	100 mW ⁽³⁾

Notes:

- (1) Measured with input leads and output leads shorted.
- (2) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
- (3) Derate linearly 1.66 mW/ $^\circ\text{C}$ above 25°C .
- (4) UL recognition is for 3500 VAC, 1 minute only.

Typical Performance Curves



Types OPI7002, OPI7010

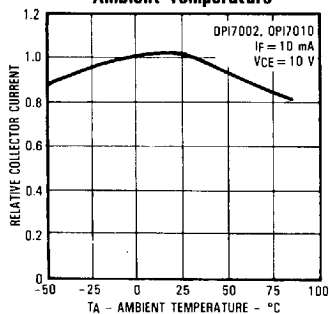
6798580 0002724 822

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

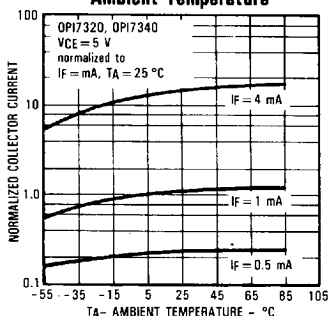
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage			1.70	V	$I_F = 10\text{ mA}$
I_R	Reverse Current			100	μA	$V_R = 2\text{ V}$
Output Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30.0			V	$I_C = 100\text{ }\mu\text{A}$, $I_F = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5.0			V	$I_E = 100\text{ }\mu\text{A}$, $I_F = 0$
I_{CEO}	Collector Dark Current			100	nA	$V_{CE} = 10\text{ V}$, $I_F = 0$
Coupled						
I_C/I_F	DC Current Transfer Ratio	OPI7002 OPI7010	20 100		% %	$I_F = 10\text{ mA}$, $V_{CE} = 5\text{ V}$ $I_F = 10\text{ mA}$, $V_{CE} = 5\text{ V}$
V_{CE}	Collector-Emitter Saturation Voltage			0.40	V	$I_F = 10\text{ mA}$, $I_C = 0.50\text{ mA}$
V_{ISO}	Isolation Voltage	6			kVDC	(See Note 1)
t_{ON}	Turn-On Time		4.0		μs	$V_{CE} = 10\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\text{ }\Omega$
t_{OFF}	Turn-Off Time		3.0		μs	$V_{CE} = 10\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\text{ }\Omega$
C_{IO}	Capacitance Input-to-Output		0.20		pF	$V_{IO} = 0$, $f = 1\text{ MHz}^{(1)}$

Typical Performance Curves

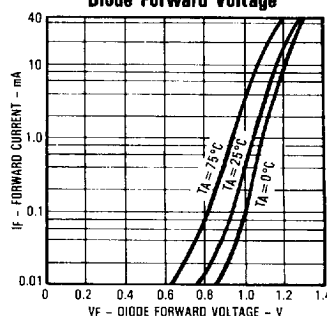
Relative Collector Current vs Ambient Temperature



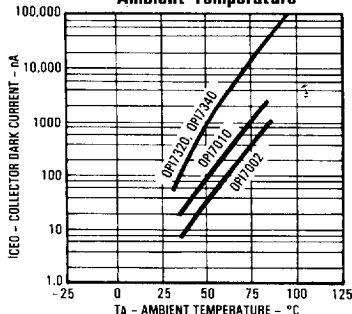
Normalized Collector Current vs Ambient Temperature



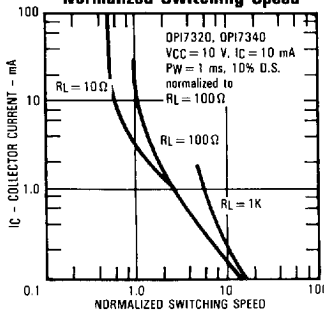
Diode Forward Current vs Diode Forward Voltage



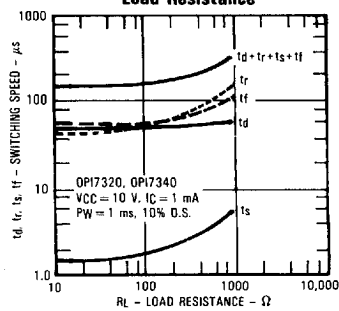
Collector Dark Current vs Ambient Temperature



Collector Current vs Normalized Switching Speed



Switching Speed vs Load Resistance



Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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